

SEMICONDUCTOR TECHNICAL DATA

SMAB110

SCHOTTKY BARRIER TYPE DIODE

SWITCHING TYPE POWER SUPPLY APPLICATIONS.

FEATURES

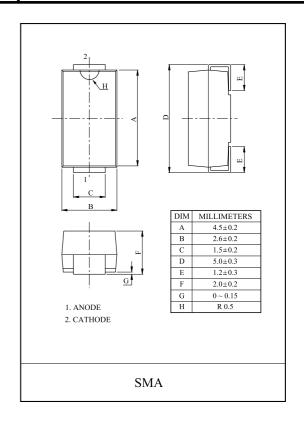
- · Low Profile Surface Mount Package.
- · Low Power Loss, High Efficiency.
- For Use in Low Voltage, High Frequency inverters, Free Wheeling, and Polarity Protection Applications.

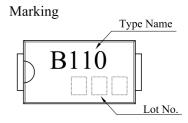
APPLICATION

- · Switching Power Supply.
- · DC/DC Converter.
- · Home Appliances, Office Equipment.
- · Telecommunication.

MAXIMUM RATING (Ta=25)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	V
Average Output Rectitifed Current	I _O	1	A
Peak One Cycle Surge Forward Current (Non-Repetitive 60Hz)	I_{FSM}	30	A
Junction Temperature	T _j	-55 125	
Storage Temperature Range	T_{stg}	-55 150	





ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	V_{FM}	I _{FM} =1.0A	-	-	0.80	V
Repetitive Peak Reverse Current	I _{RRM}	V _{RRM} =Rated	-	-	1	mA
Thermal Resistance	R _{th(j-1)}	Junction to lead	-	-	23	
	R _{th(j-a)}	Junction to ambient (on alumina substrate)	-	-	108	/W

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